NSN 5961-01-058-7813

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-058-7813 **Inclosure Material:** Ceramic **Overall Length:** 0.673 inches **Overall Diameter:** Between 0.501 inches and 0.505 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Mounting hardware **Overall Width Across Flats:** Between 0.551 inches and 0.557 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 40.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0